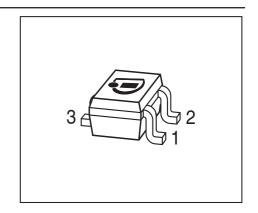


#### Low Noise Silicon Bipolar RF Transistor

- For low distortion amplifiers and oscillators up to 2 GHz at collector currents from 5 mA to 30 mA
- Pb-free (RoHS compliant) and halogen-free package with visible leads
- Qualification report according to AEC-Q101 available







### **ESD** (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration			Package
BFR93AW	R2s	1=B	2=E	3=C	SOT323

## **Maximum Ratings** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{\sf CEO}$	12	V
Collector-emitter voltage	V <sub>CES</sub>	20	
Collector-base voltage	$V_{CBO}$	20	
Emitter-base voltage	$V_{EBO}$	2	
Collector current	I <sub>C</sub>	90	mA
Base current	I <sub>B</sub>	9	
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	300	mW
<i>T</i> <sub>S</sub> ≤ 108 °C			
Junction temperature	$T_{J}$	150	°C
Ambient temperature	T <sub>A</sub>	-65 150	
Storage temperature	T <sub>Stq</sub>	-65 150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	140	K/W

1

 $<sup>{}^{1}</sup>T_{\rm S}$  is measured on the collector lead at the soldering point to the pcb

 $<sup>^2</sup>$ For calculation of  $R_{thJS}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



# **Electrical Characteristics** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	•				
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	12	-	-	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0					
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	100	μA
$V_{CE} = 20 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\rm CB} = 10 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	10	μA
$V_{\rm EB} = 2  \text{V},  I_{\rm C} = 0$					
DC current gain	h <sub>FE</sub>	70	100	140	-
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, pulse measured					



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

<b>Electrical Characteristics</b> at $T_A$ = 25 °C, unless <b>Parameter</b>	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics (verified by random sampling	g)		1		
Transition frequency	$f_{T}$	4.5	6	-	GHz
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $f$ = 500 MHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.58	0.8	pF
$V_{\text{CB}} = 10 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0$ ,					
emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.3	-	
$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
base grounded					
Emitter-base capacitance	C <sub>eb</sub>	-	1.9	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$ ,					
collector grounded					
Minimum noise figure	<i>NF</i> <sub>min</sub>				dB
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
f = 900 MHz		-	1.5	-	
f = 1.8 GHz		-	2.6	-	
Power gain, maximum available <sup>1)</sup>	G <sub>ma</sub>				
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ , $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,					
f = 900 MHz		-	15.5	-	
f = 1.8 GHz		-	10.5	-	
Transducer gain	S <sub>21e</sub>   <sup>2</sup>				dB
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 900 MHz		_	13	_	
f = 1.8 MHz		-	7.5	_	
Third order intercept point at output <sup>2)</sup>	IP <sub>3</sub>	-	15	-	dBm
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 0.9 GHz					
1dB Compression point	P <sub>-1dB</sub>	-	6	-	
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,	.35				
f = 0.9 GHz					

 $<sup>^{1}</sup>G_{\text{ma}} = |S_{21e} / S_{12e}| (k-(k^{2}-1)^{1/2})$ 

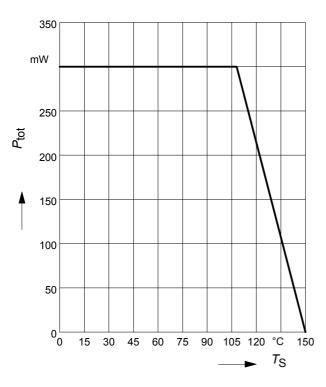
<sup>&</sup>lt;sup>2</sup>IP3 value depends on termination of all intermodulation frequency components.

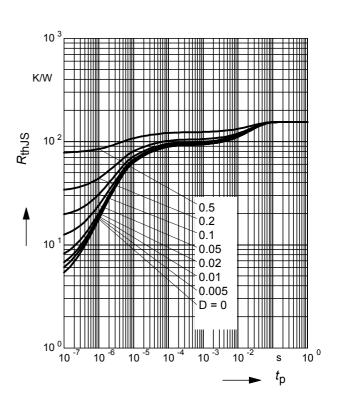
Termination used for this measurement is  $50\Omega$  from 0.2 MHz to 12 GHz



# Total power dissipation $P_{\text{tot}} = f(T_{\text{S}})$

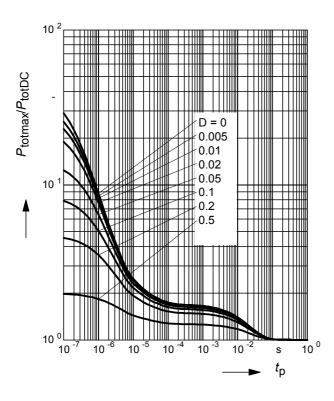
## Permissible Pulse Load $R_{thJS} = f(t_p)$





#### **Permissible Pulse Load**

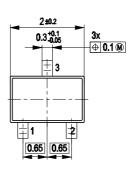
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$$

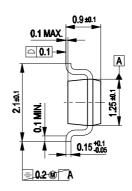




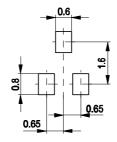
## Package Outline



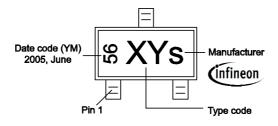




#### **Foot Print**

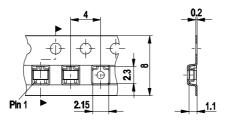


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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